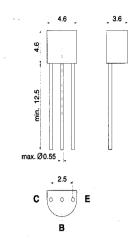
NPN Silicon Expitaxial Planar Transistor

These transistors are subdivided into three groups A, B and C according to their current gain. The type BC546 is available in groups A and B, however, the types BC547 and BC548 can be supplied in all three groups. The BC549 is a low-noise type and available in groups B and C. As complementary types, the PNP transistors BC556...BC559 are recommended.

On special request, these transistors can be manufactured in different pin configurations. Please refer to the "TO-92 TRANSISTOR PACKAGE OUTLINE" on page 80 for the available pin options.



TO-92 Plastic Package Weight approx. 0.18 g Dimensions in mm

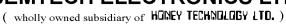
Absolute Maximum Ratings (T_a = 25°C)

		Symbol	Value	Unit
Collector-Base Voltage	HN / BC 546 HN / BC 547 HN / BC 548, HN / BC 549	V _{CBO} V _{CBO}	80 50 30	V V V
Collector-Emitter Voltage	HN / BC 546 HN / BC 547 HN / BC 548, HN / BC 549	V _{CES} V _{CES} V _{CES}	85 50 30	V V V
Collector-Emitter Voltage	HN / BC 546 HN / BC 547 HN / BC 548, HN / BC 549	HN / BC 546 V _{CEO} HN / BC 547 V _{CEO}		V V V
Emitter-Base Voltage	HN / BC 546, HN / BC 547 HN / BC 548, HN / BC 549	V _{EBO}	6 5	V V
Collector Current		I _c	100	mA
Peak Collector Current		I _{CM}	200	mA
Peak Base Current		I _{BM}	200	mA
Peak Emitter Current		-I _{EM}	200	mA
Power Dissipation at T _{amb} = 25 °C		P _{tot}	500¹)	mW ⁻
Junction Temperature		T _j	150	°C
Storage Temperature Range		T _s	-65 to + 150	°C
1) Valid provided that leads a	re kept at ambient temperature at a	a distance of 2 mm fr	om case	

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Characteristics at T_{amb} =25 °C

		Symbol	Min.	Тур.	Max.	Unit
h-Parameters at V _{CE} = 5V, I _C	= 2 mA,					
f = 1 kHz, Small Signal Current Gain	Current Gain Group A B C	h _{fe} h _{fe} h _{fe}	- -	220 330 600	- -	
Input Impedance	Current Gain Group A B C	h _{ie} h _{ie}	1.6 3.2 6	2.7 4.5 8.7	4.5 8.5 15	kΩ kΩ kΩ
Output Admittance	Current Gain Group A B C	h _{oe} h _{oe}	- - -	18 30 60	30 60 110	μS μS μS
Reverse Voltage Transfer Ra						
	Current Gain Group A B C	h _{re} h _{re} h _{re}	- - -	1.5 · 10 ⁻⁴ 2 · 10 ⁻⁴ 3 · 10 ⁻⁴	- - -	- - -
DC Current Gain. at $V_{CE} = 5V$, $I_{C} = 10 \mu A$	Current Gain Group A	h	_	90	_	_
at V = 5V = 2 mA	B C	h _{FE} h _{FE} h _{FE}	- -	150 270	- -	-
at $V_{CE} = 5V$, $I_{C} = 2 \text{ mA}$	Current Gain Group A B C	h _{FE} h _{FE} h _{FE}	110 200 420	180 290 500	220 450 800	- - -
at $V_{CE} = 5V$, $I_{C} = 100 \text{ mA}$	Current Gain Group A B C	h _{FE} h _{FE}	- - -	120 200 400	- - -	- - -
Thermal Resistance Junction to Ambient Air		R _{thA}	-		250¹)	K/W
Collector Saturation Voltage at $I_C = 10$ mA, $I_B = 0.5$ mA at $I_C = 100$ mA, $I_B = 5$ mA		V _{CEsat}	-	80 200	200 600	mV mV
Base Saturation Voltage at $I_C = 10$ mA, $I_B = 0.5$ mA at $I_C = 100$ mA, $I_B = 5$ mA		V BEsat VBEsat	- ·	700 900	-	mV mV
Base Emitter Voltage at $V_{CE} = 5 \text{ V}$, $I_{C} = 2 \text{ mA}$ at $V_{CE} = 5 \text{ V}$, $I_{C} = 10 \text{ mA}$		V _{BE}	580 -	660 -	700 720	mV mV
Collector Emitter Cutoff Curr at $V_{CE} = 80 \text{ V}$ at $V_{CE} = 50 \text{ V}$	ent HN / BC 546 HN / BC 547	CES CES	-	0.2 0.2	15 15	nA nA
at $V_{CE} = 30 \text{ V}$	/ BC 548, HN / BC 549	I _{CES}	-	0.2	15	nA
				i i		

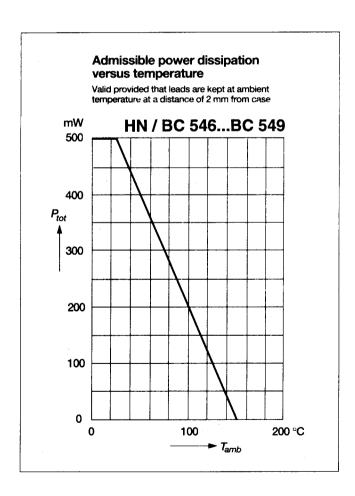


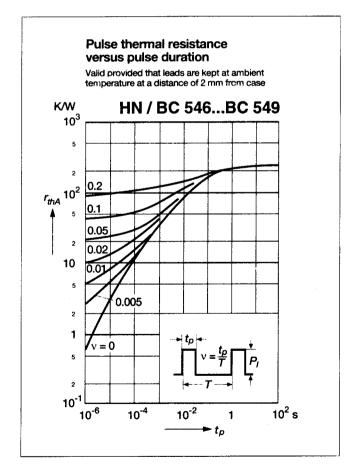




Characteristics, continuation

	Symbol	Min.	Тур.	Max.	Unit
at $V_{CE} = 30V$, $T_j = 125 °C$ HN / BC 548, HN / BC 549	I _{CES}	-	-	4 4	μ Α μ Α
Gain-Bandwidth Product at $V_{CE} = 5V$, $I_{C} = 10$ mA, $f = 100$ MHz	f _T	-	300	-	MHz
Collector-Base Capacitance at V _{CB} = 10 V, f = 1MHz	С _{сво}	-	3.5	6	pF
Emitter-Base Capacitance at V _{EB} = 0.5 V, f = 1MHz	C _{EBO}	-	9	-	pF
Noise Figure at $V_{CE} = 5 \text{ V}$, $I_{C} = 200 \mu\text{A}$, $R_{G} = 2 \text{ k}\Omega$, $f = 1 \text{kHz}$, $\Delta f = 200 \text{ Hz}$ HN / BC 546, HN / BC 547	F	-	2	10	dB
HN / BC 548 HN / BC 549	F	-	1.2	- 4	dB

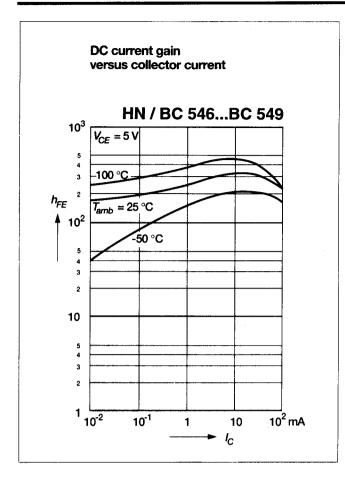


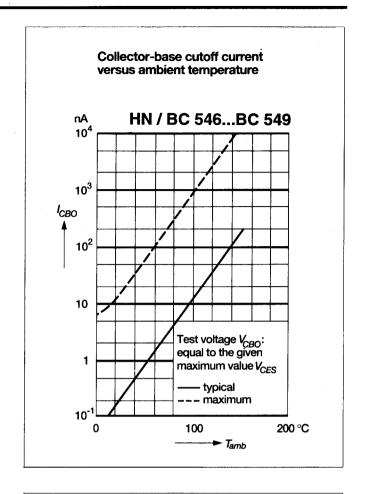


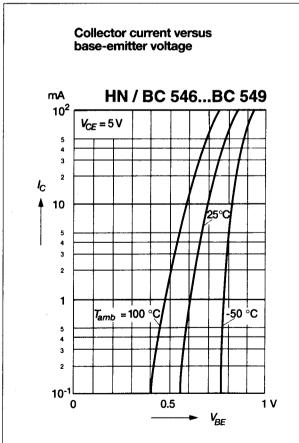


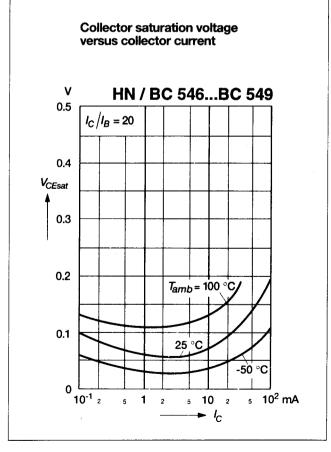
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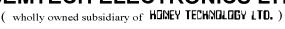




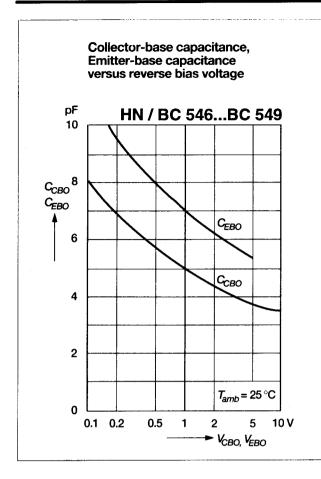


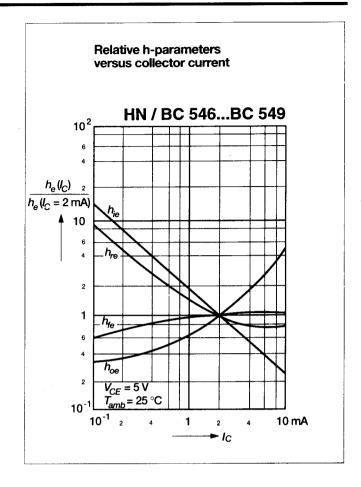


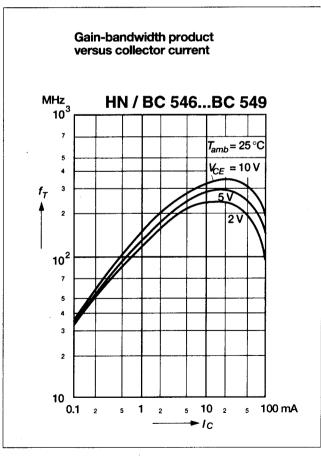
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